NSN 5962-01-179-3618

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View Online at https://aerobasegroup.com/nsn/5962-01-179-3618

Body Length: 1.290 inches Body Width: Between 0.500 inches and 0.610 inches Body Height:

0.210 inches

Maximum Power Dissipation Rating:

1.8 watts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+125.0 degrees celsius

End Application:

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Features Provided:

Hermetically sealed and burn in and erasable and programmable and positive outputs

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

21 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

6.0 volts power source

Time Rating Per Chacteristic:

300.00 nanoseconds propagation delay time, low to high level output and 300.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Rom

Test Data Document:

07187-8001760 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

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